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EE 303 Midterm Spring 2007

Open book, open notes. Only signed exam books, certifying all work is your own, will be graded. Be sure to show your reasoning for partial credit.

1. (50 points)

For the following circuit the diode is assumed to be described by the equation

$$\mathbf{i} = \begin{pmatrix} 0 & \text{if } \mathbf{v} \le \mathbf{0} \\ 2 \cdot 10^{-3} \cdot \mathbf{v} & \text{if } \mathbf{v} \ge \mathbf{0} \end{pmatrix}$$

and Vdd=5V, C=10pFd, $v_{in}(t)=0.0001\sin(2\pi 10^6 t)$.



- a) Find R to give a Q point having $I_Q = 3mA$
- b) Draw the small signal equivalent circuit and give the admittance function Y(s)=Iin(s)/Vin(s)
- c) Calculate the small signal current $i_{in}(t)$.
- 2. (50 points)

For the following circuit KPn=KPp= $2x10^{-4}$, VTOn=-VTOp=1V, $\lambda n = \lambda p = 0$, and W/L=1 for all transistors.

- a) Assuming the potential of the drain of Mm is close to VDD find the output current, Iout. Repeat if the Mm's drain potential is near ground.
- b) If VTOp changes by 10 % to VTOp' = -1.1 find the new value of Iout when the potential of the drain of Mm is close to VDD.

